Unit: mm

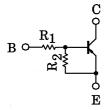
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

### RN2314,RN2315,RN2316,RN2317,RN2318

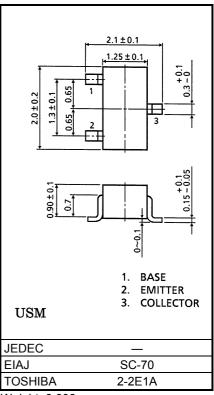
Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1314~RN1318

#### **Equivalent Circuit and Bias Resistor Values**



Type No.	R <sub>1</sub> (kΩ)	$R_2$ (k $\Omega$ )
RN2314	1	10
RN2315	2.2	10
RN2316	4.7	10
RN2317	10	4.7
RN2318	47	10



Weight: 0.006g

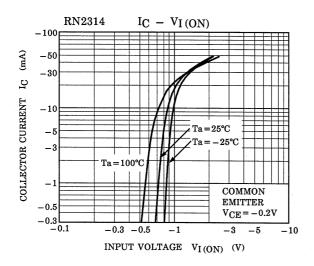
## Maximum Ratings (Ta = 25°C)

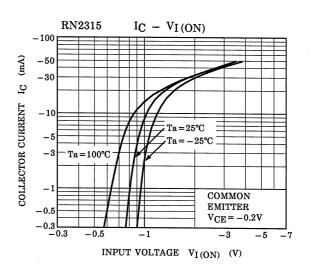
Characteristi	Symbol	Rating	Unit		
Collector-base voltage	RN2314~2318	V <sub>CBO</sub>	-50	V	
Collector-emitter voltage	KN2314~2316	V <sub>CEO</sub>	-50	V	
Emitter-base voltage	RN2314 RN2315		-5		
			-6		
	RN2316	V <sub>EBO</sub>	-7	V	
	RN2317		-15		
	RN2318	•	-25		
Collector current		Ic	-100	mA	
Collector power dissipation	RN2314~2318	PC	100	mW	
Junction temperature	KN2314~2316	Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	

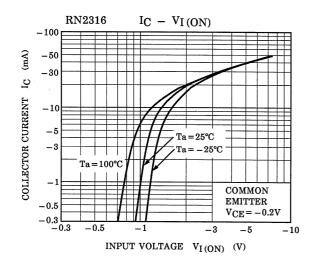


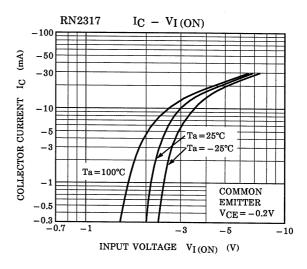
# Electrical Characteristics (Ta = 25°C)

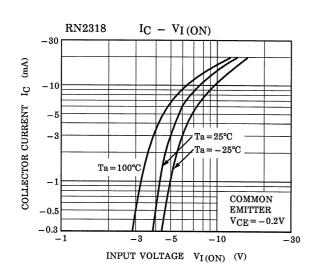
Characteri	stic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN2314~2318	I <sub>CBO</sub>	_	V <sub>CB</sub> =-50V, I <sub>E</sub> = 0	_	_	-100	nA
	RN2314~2318	I <sub>CEO</sub>	_	V <sub>CE</sub> = -50V, I <sub>B</sub> = 0	_	_	-500	nA
	RN2314	I <sub>EBO</sub>	_	$V_{EB} = -5V, I_C = 0$	-0.35	_	-0.65	mA
	RN2315		_	$V_{EB} = -6V, I_C = 0$	-0.37	_	-0.71	
Emitter cut-off current	RN2316		_	$V_{EB} = -7V, I_{C} = 0$	-0.36	_	-0.68	
	RN2317		_	V <sub>EB</sub> = −15V, I <sub>C</sub> = 0	-0.78	_	-1.46	
	RN2318		_	V <sub>EB</sub> = −25V, I <sub>C</sub> = 0	-0.33	_	-0.63	
DC gurrant gain	RN2314~16, 18	h <sub>FE</sub>	_	V <sub>CE</sub> = -5V, I <sub>C</sub> = -10mA	50	_	_	_
DC current gain	RN2317		_		30	_	_	
Collector-emitter saturation voltage	RN2314~2318	V <sub>CE</sub> (sat)	_	I <sub>C</sub> = -5mA, I <sub>B</sub> = -0.25mA	_	-0.1	-0.3	V
	RN2314		_		-0.5	_	-2.0	V
	RN2315		_		-0.6	_	-2.5	
Input voltage (ON)	RN2316	V <sub>I (ON)</sub>	_	$V_{CE} = -0.2V$ , $I_{C} = -5mA$	-0.7	_	-2.5	
	RN2317		_		-1.5	_	-3.5	
	RN2318		_		-2.5	_	-10.0	
Input voltage (OFF)	RN2314	VI (OFF)	_	V <sub>CE</sub> = -5V, I <sub>C</sub> = -0.1mA	-0.3	_	-0.9	V
	RN2315		_		-0.3	_	-1.0	
	RN2316		_		-0.3	-	-1.1	
	RN2317		_		-0.3	_	-3.0	
	RN2318		_		_	-5.7		
Translation frequency	RN2314~2318	f <sub>T</sub>	_	V <sub>CE</sub> = −10V, I <sub>C</sub> = −5mA	_	200	_	MHz
Collector output capacitance	RN2314~2318	C <sub>ob</sub>	_	V <sub>CB</sub> = -10V, I <sub>E</sub> = 0, f = 1MHz	_	3.0	6.0	pF
	RN2314	R <sub>1</sub>	_		0.7	1.0	1.3	
Input resistor	RN2315		_		1.54	2.2	2.86	
	RN2316		_	_	3.29	4.7	6.11	kΩ
	RN2317		_		7.0	10.0	13.0	
	RN2318		_		32.9	47.0	61.1	
Resistor ratio	RN2314	R <sub>1</sub> /R <sub>2</sub>	_		_	0.1	_	
	RN2315		_		_	0.22	_	
	RN2316		_	_	_	0.47	_	
	RN2317		_		_	2.13	_	
	RN2318		_		_	4.7	_	



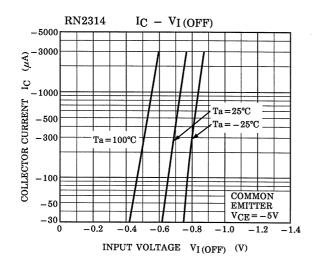


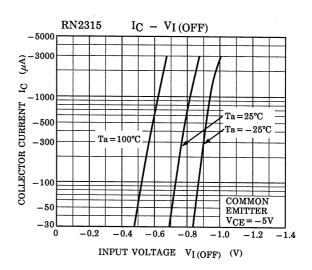


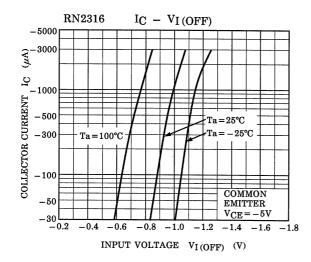


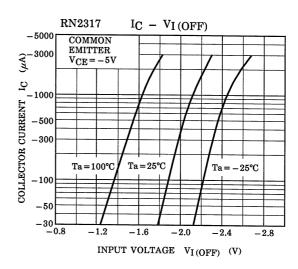


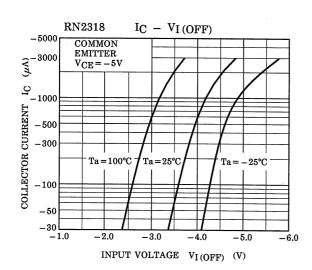
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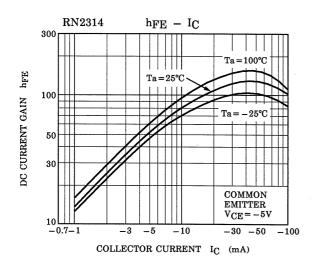


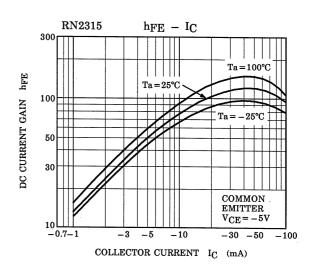


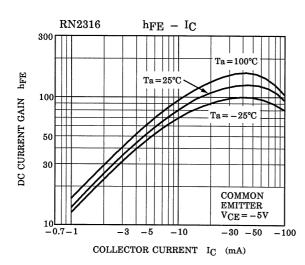


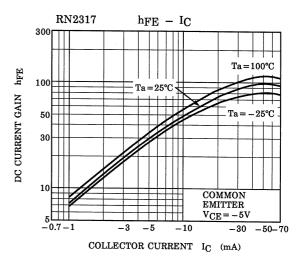


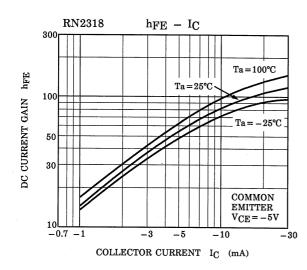
4 2001-06-07



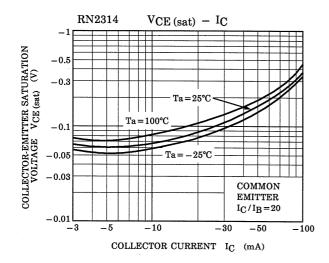


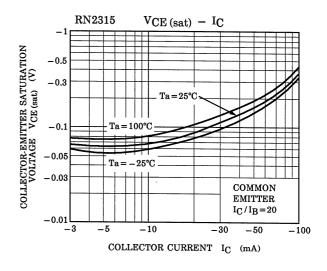


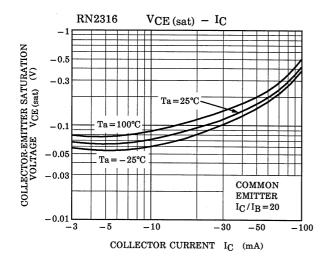


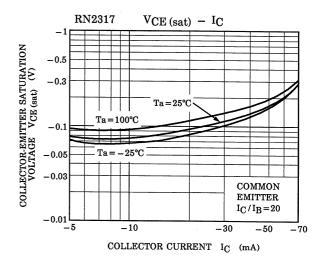


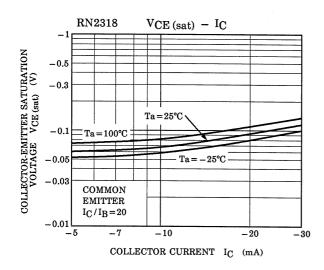
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Type Name	Marking	
RN2314	Type Name Y Q	
RN2315	Type Name	
RN2316	Type Name	
RN2317	Type Name	
RN2318	Type Name	

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000707EAA

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